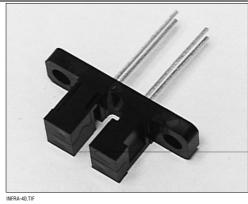
Transmissive Sensor

FEATURES

- Phototransistor output
- · Accurate position sensing
- · Choice of detector aperture
- 0.125 in.(3.18 mm) slot width
- Dust protective housing



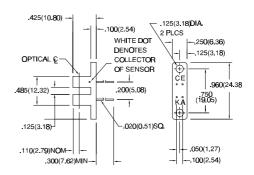
DESCRIPTION

The HOA1879 series consists of an infrared emitting diode facing an NPN silicon phototransistor encased in a black IR transmissive thermoplastic housing. Detector switching takes place whenever an opaque object passes through the slot between emitter and detector. The HOA1879 series employs an IR transmissive housing which features smooth optical faces without external aperture openings; this feature is desirable when aperture blockage from airborne contaminants is a possibility. The HOA1879-011 and -012 have a 0.060 in.(1.52 mm) dia. detector aperture, while the HOA1879-015 has a 0.010 in.(.25 mm) x 0.040 in. (1.02 mm) vertical aperture in front of the detector. This feature is ideal for use in applications where maximum position resolution is desired. The HOA1879 series employs plastic molded components. For additional component information see SEP8506 and SDP8406.

Housing material is IR transmissive polysulfone. Housings are soluble in chlorinated hydrocarbons and ketones. Recommended cleaning agents are methanol and isopropanol.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM 051 cdr

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Transmissive Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

| PARAMETER | SYMBOL | MIN | TYP | MAX | UNITS | TEST CONDITIONS |
|--------------------------------------|---------------------------------|--------|-----|-----|-------|------------------------------------------|
| | CTMBGE | 141114 | | шдд | ONTO | TEGT GORDINGRO |
| IR EMITTER | | | | | | |
| Forward Voltage | VF | | | 1.6 | V | I _F =20 mA |
| Reverse Leakage Current | I _R | | | 10 | μΑ | V _R =3 V |
| DETECTOR | | | | | | |
| Collector-Emitter Breakdown Voltage | V _(BR) ceo | 30 | | | V | Ic=100 μA |
| Emitter-Collector Breakdown Voltage | V _{(BR)ECO} | 5.0 | | | V | I _E =100 μA |
| Collector Dark Current | ICEO | | | 100 | nA | V _{CE} =10 V, I _F =0 |
| COUPLED CHARACTERISTICS | | | | | | |
| On-State Collector Current | Ic(on) | | | | mA | Vce=5 V |
| HOA1879-011 | | 0.4 | | | | I _F =20 mA |
| HOA1879-012 | | 1.8 | | | | |
| HOA1879-015 | | 0.5 | | | | |
| Collector-Emitter Saturation Voltage | Vce(sat) | | | | V | I _F =20 mA |
| HOA1879-011 | | | | 0.4 | | Ic=50 μA |
| HOA1879-012 | | | | 0.4 | | Ic=220 μA |
| HOA1879-015 | | | | 0.4 | | Ic=60 μA |
| Rise And Fall Time | t _r , t _f | | | | μs | Vcc=5 V, Ic=1 mA |
| HOA1879-011, -012, -015 | | | 15 | | | R _L =1000 Ω |

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

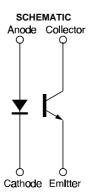
Operating Temperature Range -40°C to 85°C Storage Temperature Range -40°C to 85°C Soldering Temperature (5 sec) 240°C

IR EMITTER

Power Dissipation 100 mW (1)
Reverse Voltage 3 V
Continuous Forward Current 50 mA

DETECTOR
Collector-Emitter Voltage 30 V
Emitter-Collector Voltage 5 V

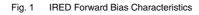
Emitter-Collector Voltage 5 V
Power Dissipation 100 mW ⁽¹⁾
Collector DC Current 30 mA

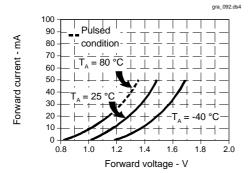


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Transmissive Sensor





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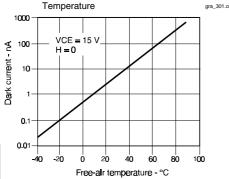
1000

Load resistance - Ohms

10000

10

Fig. 3 Dark Current vs



Collector Current vs Fig. 4 Ambient Temperature gra_095.ds4 Normalized collector current 1.0 0.6 0.4 0.2 0.0 75 -50 Ó 25 50 100

Free-air temperature - °C

All Performance Curves Show Typical Values

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